



DXT5551

#### **160V NPN TRANSISTOR IN SOT89**

### **Features**

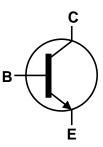
- BV<sub>CEO</sub> > 160V
- I<sub>C</sub> = 600mA High Collector Current
- Complementary PNP Type: DXT5401
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

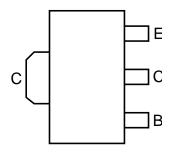
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.072 grams (Approximate)







Device Symbol



Top View Pin-Out

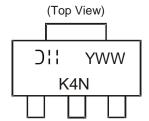
# Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT5551-13	K4N	13	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

# **Marking Information**



K4N = Product Type Marking Code: YWW = Date Code Marking Y = Last digit of year ex: 1 = 2011 WW = Week code 01 - 52



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	Ic	600	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	Б	0.75	w	
Power Dissipation	(Note 6)	P <sub>D</sub>	1.2		
Thermal Resistance, Junction to Ambient Air	(Note 5)	Б	166	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ hetaJA}$	104		
Operating and Storage Temperature Range	T <sub>i</sub> , T <sub>STG</sub>	-55 to +150	°C		

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

<sup>5.</sup> For a device mounted with the exposed collector pad on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

<sup>6.</sup> Same as note (5), except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.

<sup>7.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.

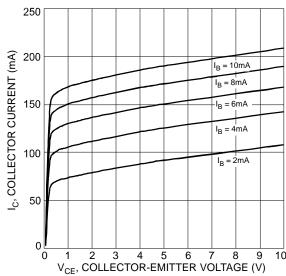


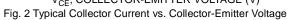
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

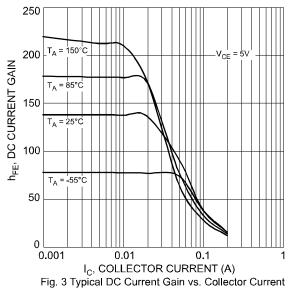
Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS					
BV <sub>CBO</sub>	180	_	_	V	$I_{C} = -100 \mu A$
BV <sub>CEO</sub>	160	_	_	V	I <sub>C</sub> = -10mA
BV <sub>EBO</sub>	6.0	_	_	V	$I_E = -100 \mu A$
	_	_	50	nA	V <sub>CB</sub> = 120V
ICBO			50	μA	V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
I <sub>EBO</sub>	1	_	50	nA	V <sub>EB</sub> = 4V
	80		_		$I_C = 1mA$ , $V_{CE} = 5V$
h <sub>FE</sub>	80	_	250	_	$I_C = 10$ mA, $V_{CE} = 5$ V
	30		_		$I_C = 50$ mA, $V_{CE} = 5$ V
Voru	_	_	0.15 0.20	W	$I_C = 10mA$ , $I_B = 1mA$
VCE(sat)				V	$I_C = 50$ mA, $I_B = 5$ mA
V <sub>BE(sat)</sub>	_	_	1.0	V	$I_C = 10mA$ , $I_B = 1mA$
					$I_C = 50$ mA, $I_B = 5$ mA
SMALL SIGNAL CHARACTERISTICS					
f <sub>T</sub>	100	_	300	MHz	$I_C = 10 \text{mA}, V_{CE} = 10 \text{V},$ f = 100 MHz
C <sub>obo</sub>	_	_	6	pF	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$
h <sub>fe</sub>	50		200	_	V <sub>CB</sub> = 10V, I <sub>C</sub> = 1mA, f = 1kHz
NF	_	_	8	dB	$V_{CB} = 5V$ , $I_C = 200\mu A$ , $R_S = 1k\Omega$ , $f = 1kHz$
	BV <sub>CBO</sub> BV <sub>EBO</sub> BV <sub>EBO</sub> ICBO IEBO  VCE(sat)  VBE(sat)  f <sub>T</sub> C <sub>Obo</sub> h <sub>fe</sub>	BVCBO 180 BVCEO 160 BVEBO 6.0  ICBO —  IEBO —  80 A80 30  VCE(sat) —  VBE(sat) —  fT 100  Cobo —  hfe 50	BV <sub>CBO</sub> 180 — BV <sub>CEO</sub> 160 — BV <sub>EBO</sub> 6.0 — ICBO — — IEBO — —  NFE 80 — 30  VCE(sat) — —  VBE(sat) — —  f <sub>T</sub> 100 — C <sub>obo</sub> — — h <sub>fe</sub> 50 —	BV <sub>CBO</sub> 180 — — BV <sub>CEO</sub> 160 — — BV <sub>EBO</sub> 6.0 — — I <sub>CBO</sub> — 50 I <sub>EBO</sub> — 50  VCE(sat) — 0.15 V <sub>BE(sat)</sub> — 1.0  F <sub>T</sub> 100 — 300 C <sub>Obo</sub> — 6 h <sub>fe</sub> 50 — 200	BV <sub>CBO</sub> 180 — V BV <sub>CEO</sub> 160 — V BV <sub>EBO</sub> 6.0 — V I <sub>CBO</sub> — 50 nA I <sub>EBO</sub> — 50 nA I <sub>EBO</sub> — 50 nA VCE(sat) — 0.15 V VBE(sat) — 1.0 V F <sub>T</sub> 100 — 300 MHz C <sub>Obo</sub> — 6 pF I <sub>fe</sub> 50 — 200 —

8. Measured under pulsed conditions. Pulse width ≤ 300 µs. Duty cycle ≤ 2%.

# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

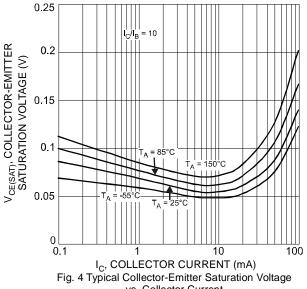


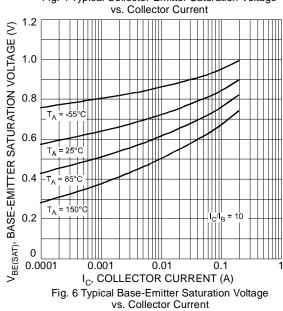




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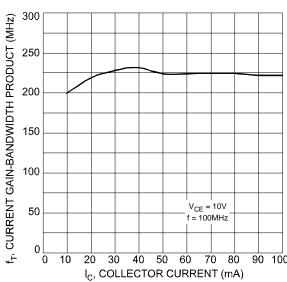


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

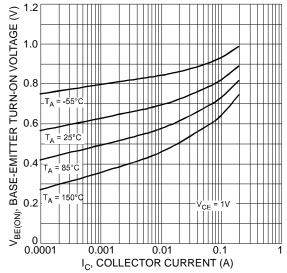


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

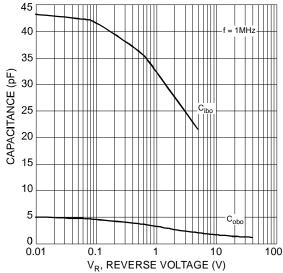
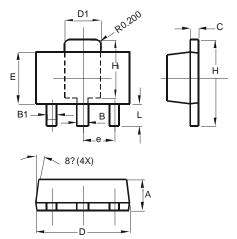


Fig. 7 Typical Capacitance Characteristics



# **Package Outline Dimensions**

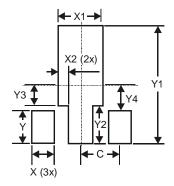
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1 500



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